

IPS1051LPbF / IPS1052GPbF

SINGLE/DUAL CHANNEL INTELLIGENT POWER LOW SIDE SWITCH

Features

- Over temperature shutdown
- Over current shutdown
- Active clamp
- Low current & logic level input
- ESD protection
- Optimized Turn On/Off for EMI
- Diagnostic on the input current

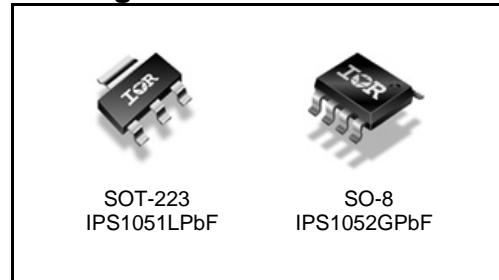
Product Summary

Rds(on)	250mΩ (max.)
Vclamp	39V
Ishutdown	2.8A (typ.)

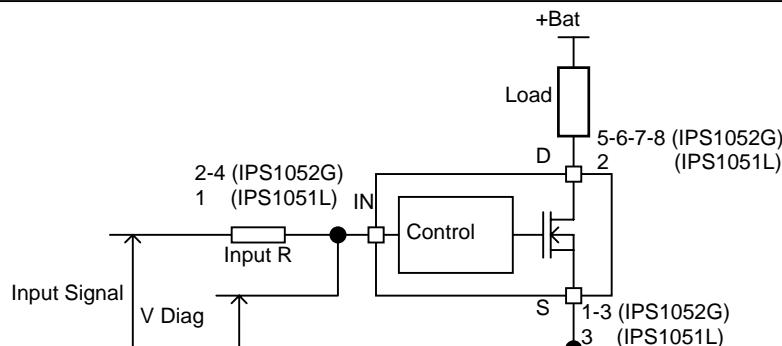
Description

The IPS1051LPbF and IPS1052GPbF are Intelligent Power Switches (IPS) featuring low side MOSFETs with over-current, over-temperature, ESD protection and drain to source active clamp. The IPS1052G is a dual channel device while the IPS1051 is a single channel. These devices offer protections and the high reliability required in harsh environments. Each switch provides efficient protection by turning OFF the power MOSFET when the temperature exceeds 165°C or when the drain current reaches 3A. The device restarts once the input is cycled. A serial resistance connected to the input provides the diagnostic. The avalanche capability is significantly enhanced by the active clamp and covers most inductive load demagnetizations.

Packages



Typical Connection



Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to Ground lead. (T_{ambient}=25°C unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
V _{ds}	Maximum drain to source voltage	-0.3	36	V
V _{ds cont.}	Maximum continuous drain to source voltage	-	28	V
V _{in}	Maximum input voltage	-0.3	6	V
I _{sd cont.}	Max diode continuous current (limited by thermal dissipation)	—	1.3	A
P _d	Maximum power dissipation (internally limited by thermal protection) R _{th} =60°C/W IPS1051L 1" sqrt. footprint	2	1.25	W
ESD	Electrostatic discharge voltage (Human body) C=100pF, R=1500Ω Between drain and source	—	4	kV
	Other combinations	—	3	
	Electrostatic discharge voltage (Machine Model) C=200pF, R=0Ω Between drain and source	—	0.5	
	Other combinations	—	0.3	
T _j max.	Max. storage & operating temperature junction temperature	-40	150	°C

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
R _{th1}	Thermal resistance junction to ambient IPS1051L SOT-223 std. footprint	100	—	°C/W
R _{th2}	Thermal resistance junction to ambient IPS1051L SOT-223 1" sqrt. footprint	60	—	
R _{th1}	Thermal resistance junction to ambient IPS1052G SO-8 std. Footprint 1 die active	100	—	
R _{th1}	Thermal resistance junction to ambient IPS1052G SO-8 std. footprint 2 die active	130	—	

Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter	Min.	Max.	Units
V _{IH}	High level input voltage	4.5	5.5	V
V _{IL}	Low level input voltage	0	0.5	
I _{ds}	Continuous drain current, T _{ambient} =85°C, T _j =125°C, V _{in} =5V R _{th} =60°C/W IPS1051L 1" sqrt. Footprint	—	1.4	A
	Continuous drain current, T _{ambient} =85°C, T _j =125°C, V _{in} =5V R _{th} =100°C/W IPS1052G 1" sqrt. Footprint - 1 die active	—	1.1	A
	Continuous drain current, T _{ambient} =85°C, T _j =125°C, V _{in} =5V R _{th} =130°C/W IPS1052G 1" sqrt. Footprint - 2 die active	—	0.5	A
R _{in}	Recommended resistor in series with IN pin to generate a diagnostic	0.5	10	kΩ
Max L	Max. recommended load inductance (including line inductance)(1)	—	30	μH
Max. F	Max. frequency	—	10	kHz
Max. t rise	Max. input rise time	—	1	μs

(1) Higher inductance is possible if maximum load current is limited - see figure 11

Static Electrical Characteristics

T_j=25°C, V_{cc}=14V (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
R _{ds(on)}	ON state resistance T _j =25°C	—	160	250	mΩ	V _{cc} =5V, I _{ds} =1A
	ON state resistance T _j =150°C	—	340	450		
I _{dss1}	Drain to source leakage current	—	0.1	5	μA	V _{cc} =14V, T _j =25°C
I _{dss2}	Drain to source leakage current	—	0.2	10		V _{cc} =28V, T _j =25°C
V clamp1	Drain to source clamp voltage 1	36	38	—	V	I _d =20mA
V clamp2	Drain to source clamp voltage 2	—	39	42		I _d =0.5A
V _{in} clamp	IN to source pin clamp voltage	5.5	6.5	7.5		I _{in} =1mA
V _{th}	Input threshold voltage	—	1.7	—		I _d =10mA

Switching Electrical Characteristics

V_{cc}=14V, Resistive load=10Ω, R_{input}=50Ω, V_{in}=5V, T_j=25°C

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T _{don}	Turn-on delay time to 20%	1	3	10	μs	See figure 2
T _r	Rise time 20% to 80%	1	3	10		
T _{doff}	Turn-off delay time to 80%	3	15	40		
T _f	Fall time 80% to 20%	2	4	10		
E _{on} + E _{off}	Turn on and off energy	—	0.1	—	mJ	

Protection Characteristics

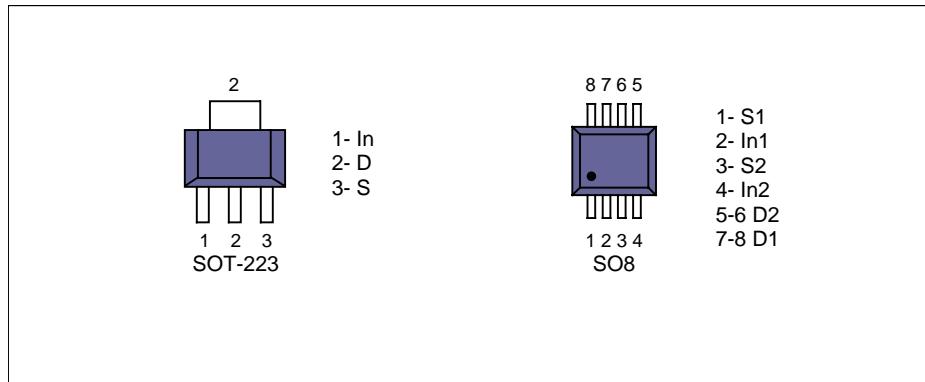
Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T _{sd}	Over temperature threshold	150(2)	165	—	°C	See figure 1
I _{sd}	Over current threshold	1.9	2.8	3.8	A	See figure 1
O _V	Over voltage protection (not active when the device is ON)	34	37	—	V	
V _{reset}	IN protection reset threshold	—	1.7	—	V	
T _{reset}	Time to reset protection	15(2)	50	200	μs	V _{in} =0V, T _j =25°C

(2)Guaranteed by design

Diagnostic

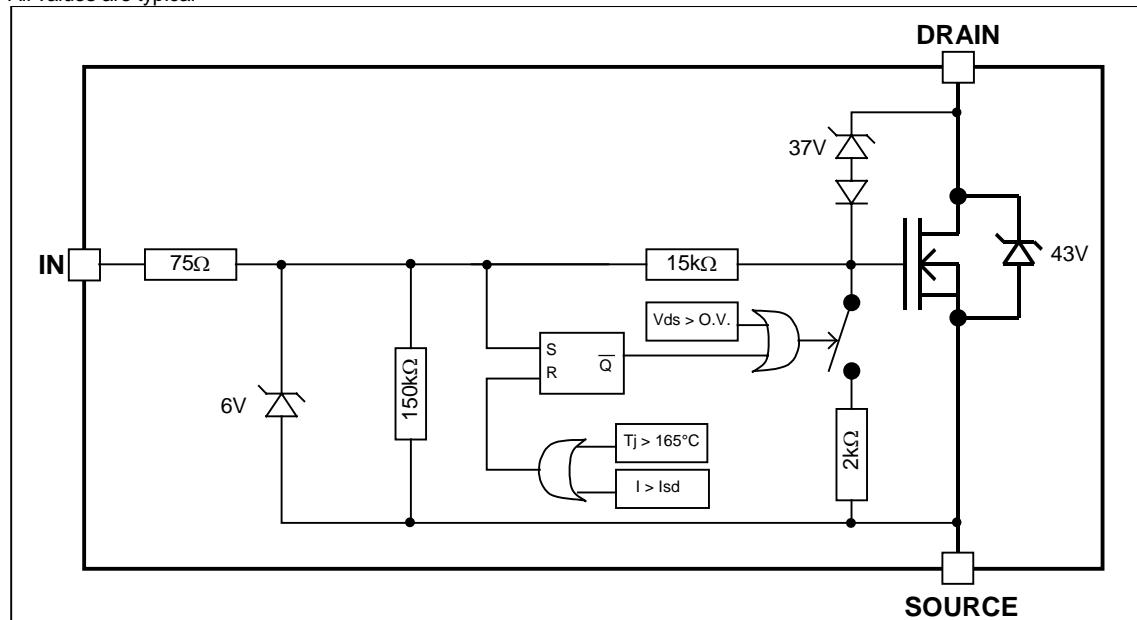
Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
I _{in, on}	ON state IN positive current	15	32	70	μA	V _{in} =5V
I _{in, off}	OFF state IN positive current (after protection latched – fault condition)	150	230	350		

Lead Assignments

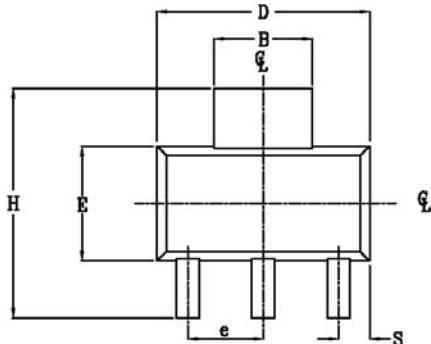


Functional Block Diagram

All values are typical

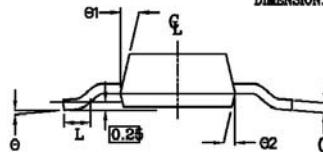
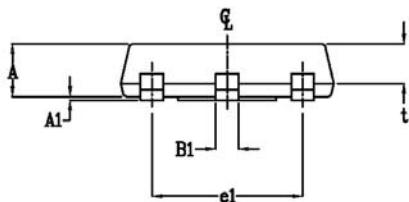


Case Outline - SOT-223 - Automotive Q100 PbF MSL2 qualified



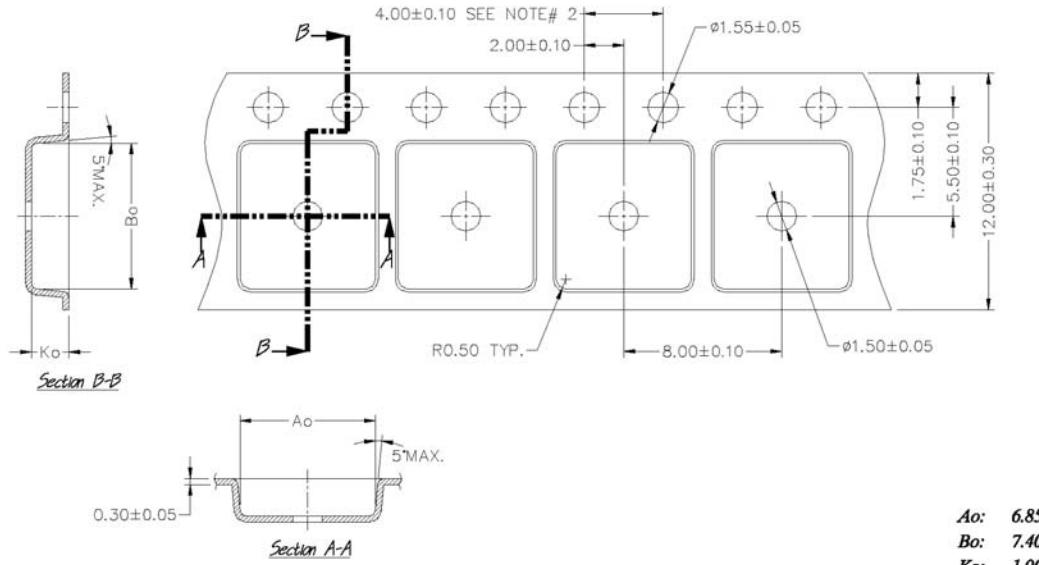
POS	MILLIMETERS		INCHES	
	MAX	MIN	MAX	MIN
A	1.70	1.50	.067	.060
A1	0.10	0.02	.004	.0008
B	3.15	2.95	.124	.116
B1	0.85	0.65	.033	.028
C	0.35	0.25	.014	.010
D	6.70	6.30	.264	.248
e	2.30 NOM		.0905 NOM	
e1	4.60 NOM		.181 NOM	
E	3.70	3.30	.146	.130
H	7.30	6.70	.287	.264
S	1.05	0.85	.041	.033
t	1.30	1.10	.051	.043
G	10° MAX		10° MAX	
G1	16°	10°	16°	10°
G2	16°	10°	16°	10°
L	0.75 MIN		0.0295 MIN	

NOTE:
 1. PACKAGE OUTLINE EXCLUSIVE OF ANY MOLD FLASHES DIMENSION.
 2. PACKAGE OUTLINE EXCLUSIVE OF BURR DIMENSION.



Leads and drain are plated with 100% Sn

Tape & Reel - SOT-223



NOTES:

1. Ao & Bo are measured at 0.3mm above base of pocket.
2. 10 pitches cumulative tol. ±0.2mm.

$Ao:$	6.85
$Bo:$	7.40
$Ko:$	1.90
$Pitch:$	8.00
$Width:$	12.00